

HA17324/A Series

Quad Operational Amplifier

HITACHI

ADE-204-031A (Z)

Rev.1

Mar. 2001

Description

HA17324 series and HA17324A series are quad operational amplifier that provide high gain and internal phase compensation, with single power supply. They can be widely used to control equipments.

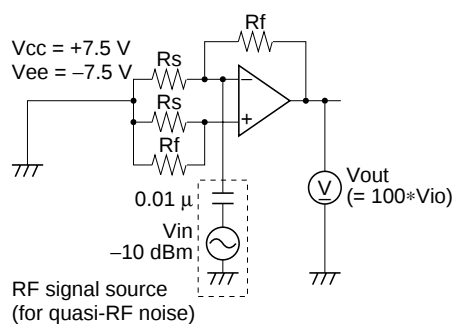
Features

- Wide range of supply voltage, and single power supply used
- Internal phase compensation
- Wide range of common mode voltage, and possible to operate with an input about 0 V

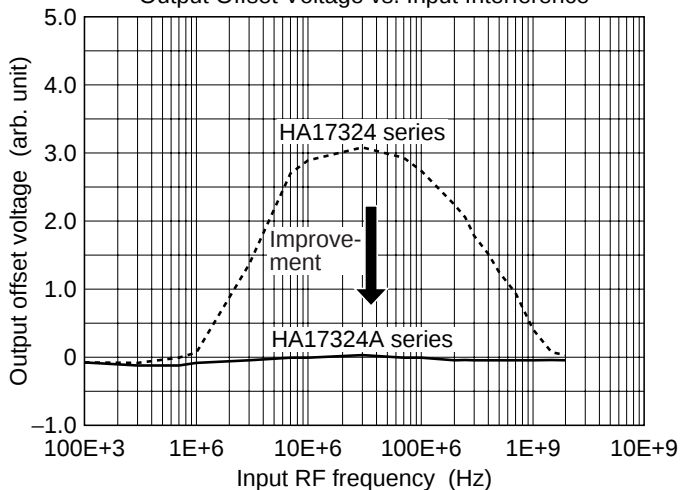
Features only for “A” series

- Low electro-magnetic susceptibility level

Measurement Condition



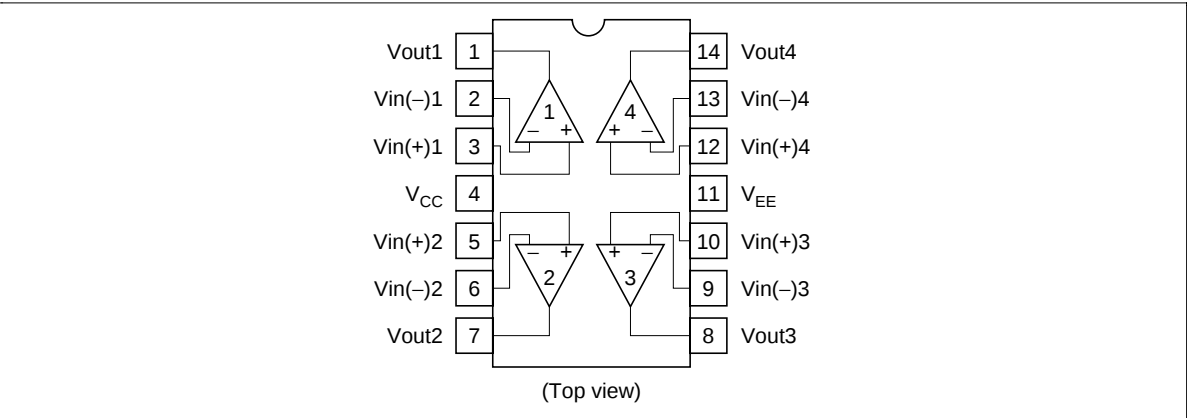
Output Offset Voltage vs. Input Interference



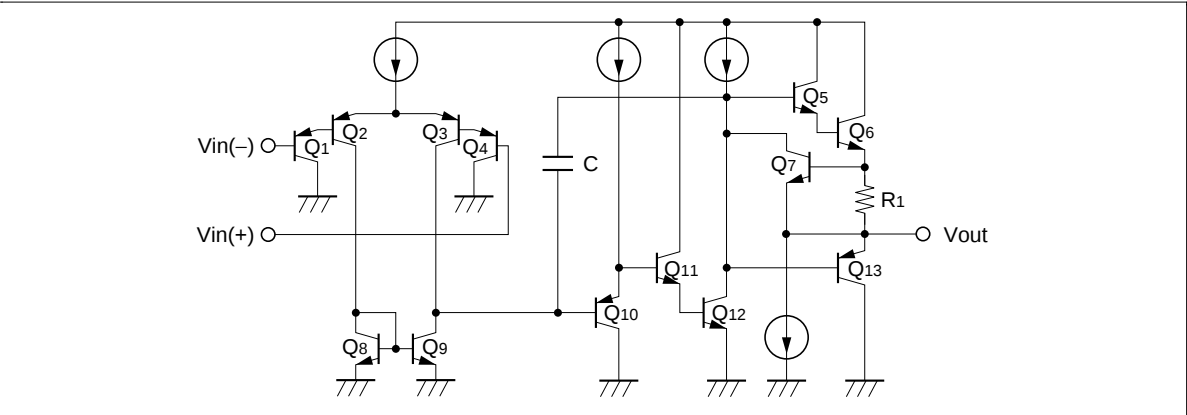
Ordering Information

Type No.	Application	Package
HA17324	Commercial use	DP-14
HA17324F		FP-14DA
HA17324P	Industrial use	DP-14
HA17324FP		FP-14DA
HA17324AP	Industrial use	DP-14
HA17324ARP	Commercial use	FP-14DN
HA17324AFP		FP-14DA

Pin Arrangement



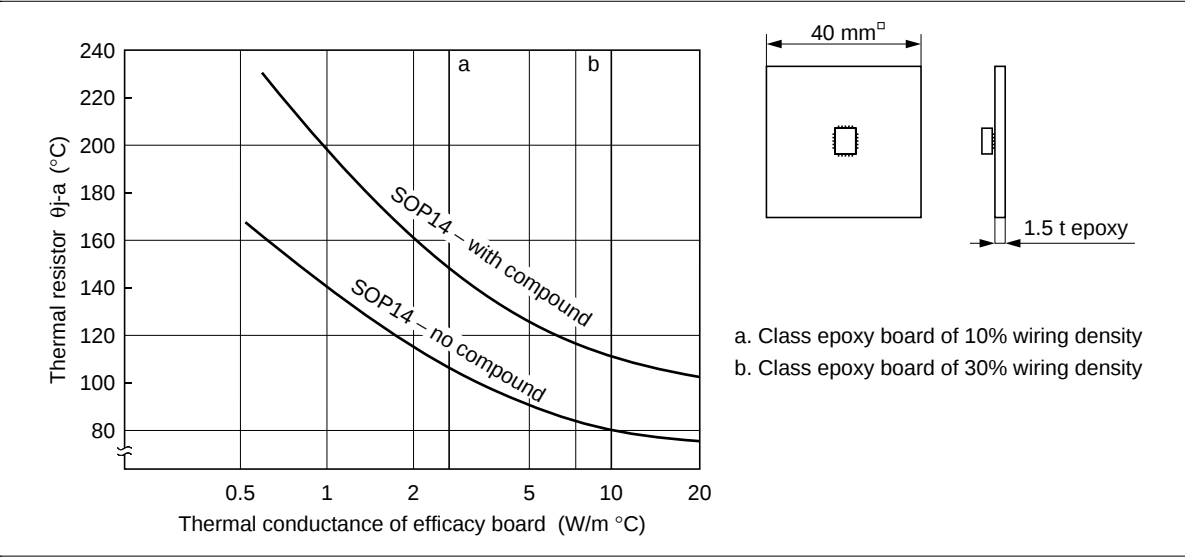
Circuit Schematic (1/4)



Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings		Unit
		HA17324/P/F/FP	HA17324AP/ARP/AFP	
Supply voltage	V _{CC}	32	32	V
Sink current	I _{sink}	50	50	mA
Power dissipation	P _T	625 * ¹	625 * ²	mW
Common mode input voltage	V _{CM}	−0.3 to V _{CC}	−0.3 to V _{CC}	V
Differential input voltage	V _{in} (diff)	±V _{CC}	±V _{CC}	V
Operating temperature	T _{opr}	−20 to +75	−40 to +85	°C
Storage temperature	T _{stg}	−55 to +125	−55 to +125	°C

Notes: 1. This is the allowable values up to Ta = 50°C. Derate by 8.3 mW/°C.
2. Tjmax = θj-a · P_Cmax + Ta (θj-a; Thermal resistor between junction and ambient at set board use).
The wiring density and the material of the set board must be chosen for thermal conductance of efficacy board.
And P_Cmax cannot be over the value of P_T.

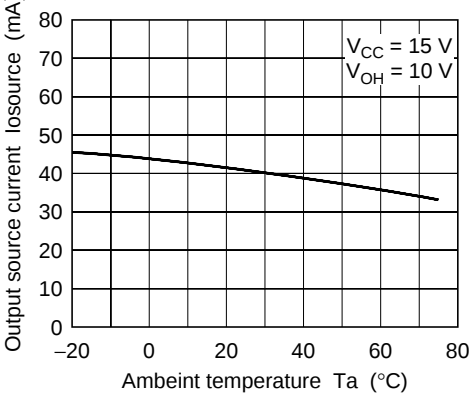


Electrical Characteristics (V_{CC} = +15 V, Ta = 25°C)

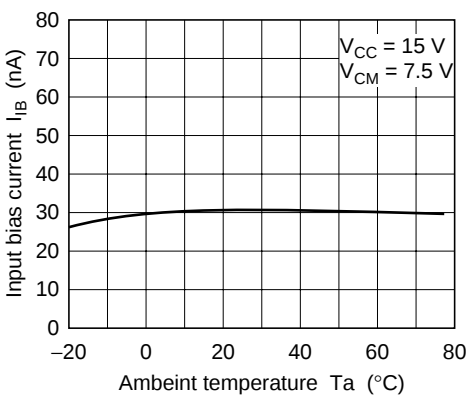
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Input offset voltage	V _{IO}	—	2	7	mV	V _{CM} = 7.5 V, R _S = 50 Ω, Rf = 50 kΩ
Input offset current	I _{IO}	—	5	50	nA	V _{CM} = 7.5 V, I _{IO} = I _{I(−)} − I _{I(+)}
Input bias current	I _{IB}	—	30	500	nA	V _{CM} = 7.5 V
Power source rejection ratio	PSRR	—	93	—	dB	f = 100 Hz, R _S = 1 kΩ, Rj = 100 kΩ
Voltage gain	A _{VD}	75	90	—	dB	R _S = 1 kΩ, Rf = 100 kΩ, R _L = ∞
Common mode rejection ratio	CMR	—	80	—	dB	R _S = 50 Ω, Rf = 5 kΩ
Common mode input voltage range	V _{CM}	−0.3	—	13.5	V	R _S = 1 kΩ, Rf = 100 kΩ, f = 100 Hz
Maximum output voltage	Vop-p	—	13.6	—	V	f = 100 Hz, R _S = 1 kΩ, Rf = 100 kΩ, R _L = 20 kΩ
Output source current	Iosource	20	40	—	mA	V _{IN} ⁺ = 1 V, V _{IN} [−] = 0 V, V _{OH} = 10 V
Output sink current	Iosink	10	20	—	mA	V _{IN} = 0 V, V _{IN} = 1 V, V _{OL} = 2.5 V
Supply current	I _{CC}	—	0.8	2	mA	V _{IN} = GND, R _L = ∞
Slew rate	SR	—	0.19	—	V/μs	f = 1.5 kHz, V _{CM} = 7.5 V, R _L = ∞
Channel separation	CS	—	120	—	dB	f = 1 kHz
Output sink current	Iosink	15	50	—	μA	V _{IN} ⁺ = 0 V, V _{IN} [−] = 1 V, V _{OL} = 200 mV
	Iosink	3	9	—	mA	V _{IN} ⁺ = 0 V, V _{IN} [−] = 1 V, V _{OL} = 1 V
Output voltage	V _{OH}	13.2	13.6	—	V	I _{OH} = −1 mA
	V _{OH}	12.0	13.3	—	V	I _{OH} = −10 mA
Output voltage	V _{OL}	—	0.8	1.0	V	I _{OL} = 1 mA
	V _{OL}	—	1.1	1.8	V	I _{OL} = 10 mA

Characteristic Curves

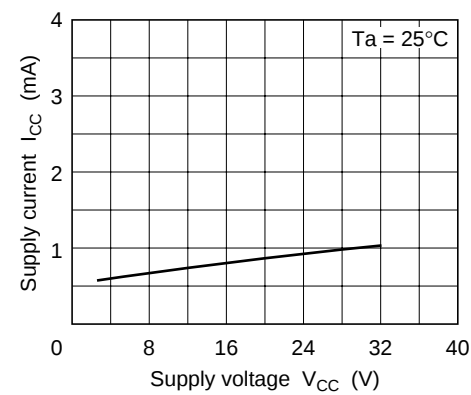
Output Source Current vs. Ambient Temperature



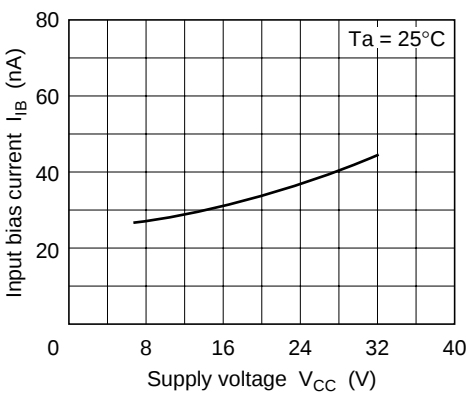
Input Bias Current vs. Ambient Temperature



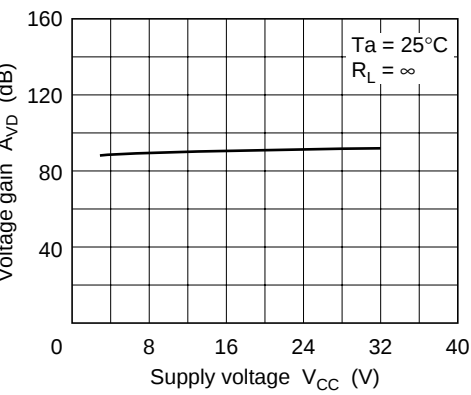
Supply Current vs. Supply Voltage



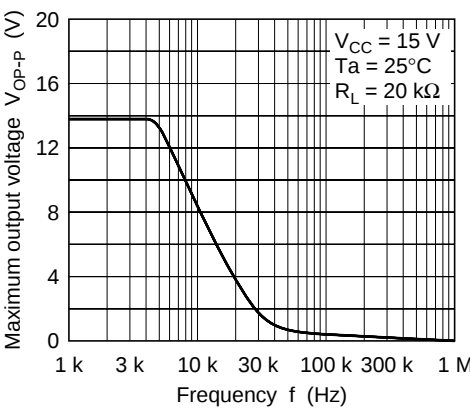
Input Bias Current vs. Supply Voltage

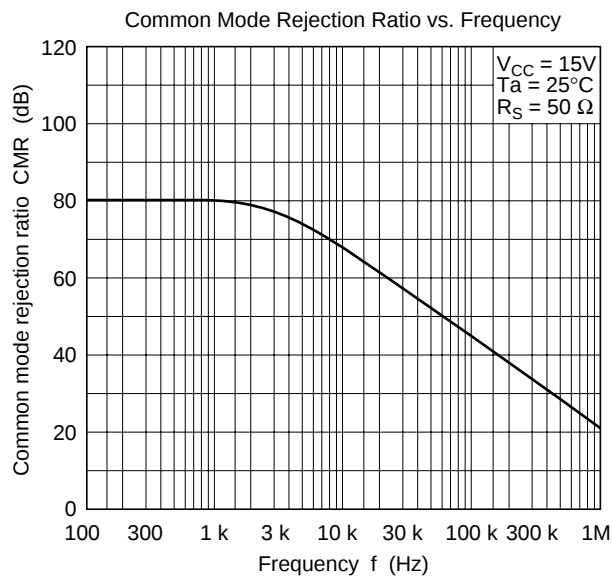
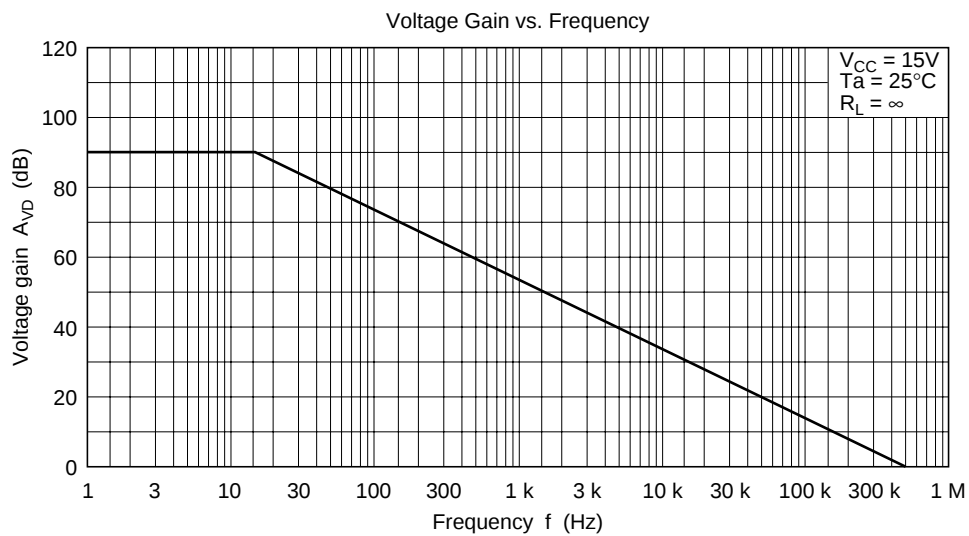


Voltage Gain vs. Supply Voltage



Maximum Output Voltage vs. Frequency





Solder Mounting Method

- 1. Small and light surface-mount packages require spicial attentions on solder mounting.
On solder mounting, pre-heating before soldering is needed.
The following figure show an example of infrared rays reflow.
- 2. The difference of thermal expansion coefficeient between mounted substrates and IC leads may cause a failure like solder peeling or soler wet, and electrical characteristics may change by thermal stress.
Therefore, mounting should be done after sufficient confirmation for especially in case of ceramic substrates.

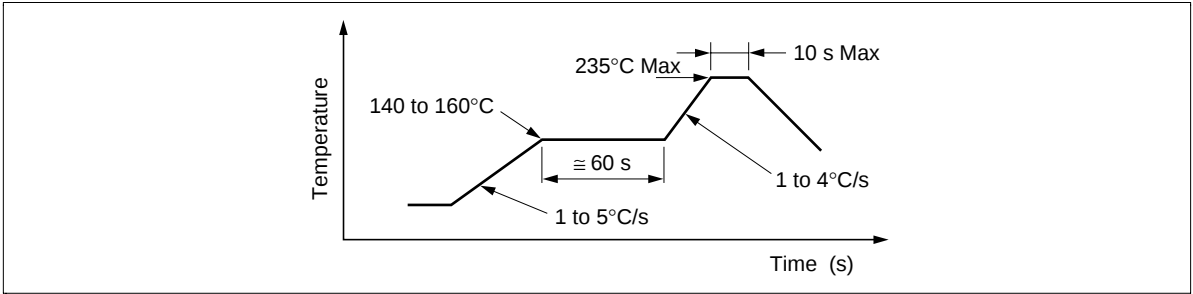
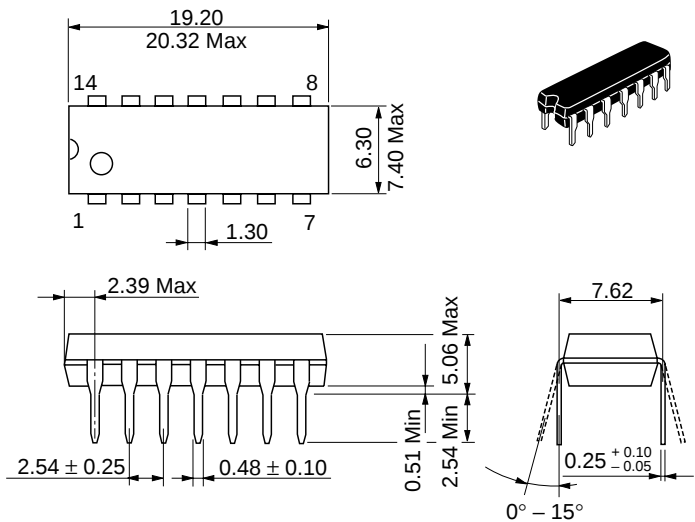


Figure 1 An Example of Infrared Rays Reflow Conditions

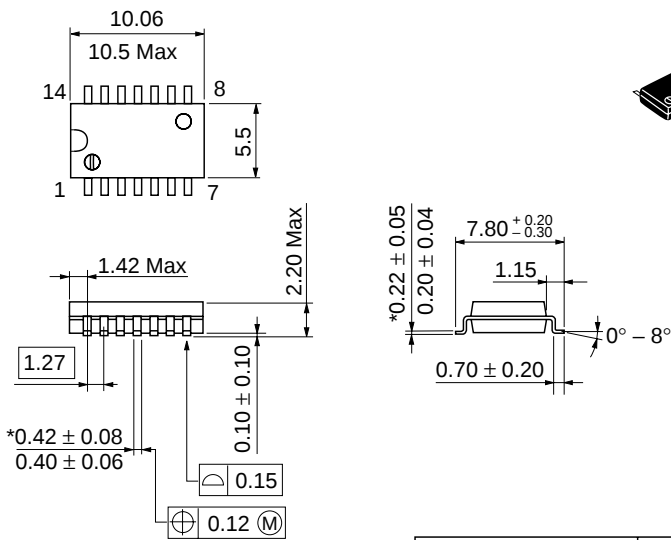
Package Dimensions

Unit: mm



Hitachi Code	DP-14
JEDEC	Conforms
EIAJ	Conforms
Mass (reference value)	0.97 g

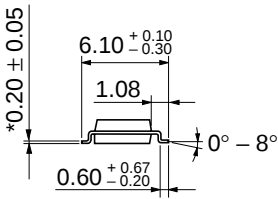
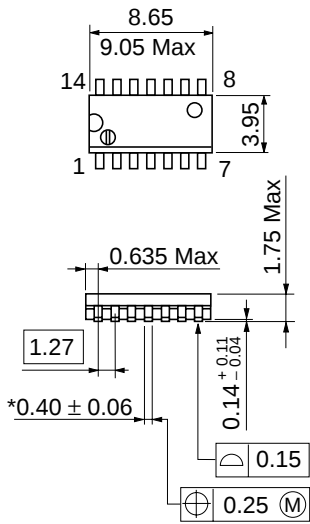
Unit: mm



*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-14DA
JEDEC	—
EIAJ	Conforms
Mass (reference value)	0.23 g

Unit: mm



*Pd plating

Hitachi Code	FP-14DN
JEDEC	Conforms
EIAJ	Conforms
Mass (reference value)	0.13 g

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